Q.P. Code: 23885

Time:-3 Hrs

3. Draw neat and clean diagrams

2. Solve any THREE out of remaining questions

N.B.: 1. Question ONE is compulsory



Marks: 80

	4. Assume suitable data if required.	
Q. 1.	A. Justify that JFET can be used as a Voltage Variable Resistor.	5
	B. Explain the ideal characteristics of op-amp	5
	C. With neat circuit diagram explain the use of PLL in frequency demodulation.	5
	D. Explain detection of pulse code modulation.	5
Q. 2	A. Explain various biasing techniques used in case of JFET.	10
	B. Explain how op-amp can be used as differentiator.	10
Q. 3	A. Explain the concept of virtual ground in operational amplifier.	5
	B. State and explain Barkhausens criteria for oscillations.	5
	C. Explain any one pulse modulation technique of your choice.	5
	D. Determine the magnitude of g_m for a JFET with $I_{DSS} = 6$ mA and $V_P = -3$ V at	
	V_{GS} = -0.5 V and also at V_{GS} = -1.5 V.	5
Q. 4	A. Explain the generation of DSBSC using balanced modulator.	10
	B. With neat diagram and waveforms explain the operating principle of PLL.	10
Q. 5	A. With block diagram describe the principle of analog communication system.	10
	B. Explain phase modulation in detail.	10
Q. 6	A. What is Nyquist Criteria? What is its significance?	5
	B. Discuss Class C power amplifier.	5
	C. Write short note on generation of FM by Armstrong method	5
	D. Mention important specifications of ADC and DAC required for communication.	5